

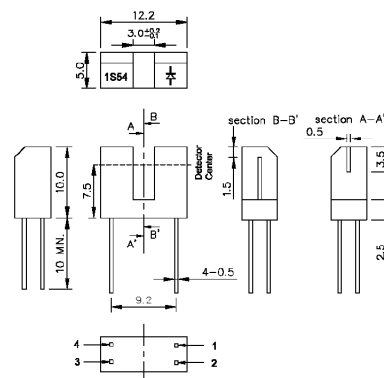
Features

1. Horizontal slit type
2. PWB direct mounting type
3. GAP between light emitter and detector : 3.0mm
4. Slit width : 0.5mm

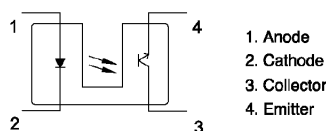
Applications

1. OA equipment, such as printer etc.
2. VCRs, cassette decks
3. Floppy disk drives

Outside Dimension:Unit (mm)



Schematic:Top View



Absolute Maximum Ratings

(Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	IF	50	mA
	Peak forward current *1	IFP	1	A
	Reverse voltage	VR	6	V
	Power dissipation	PD	75	mW
Output	Collector-emitter voltage	VCEO	35	V
	Emitter-collector voltage	VECO	6	V
	Collector current	IC	20	mA
	Power dissipation	PD	75	mW
	Total power dissipation	TPD	100	mW
	Operating temperature	TOPR	-25 to +85	°C
	Storage temperature	TSTG	-40 to +100	°C
	Soldering temperature *2	TSOL	260	°C

*1 Pulse width \leq 100 μ s, duty ratio=1%

*2 For 5 seconds

Electro-optical Characteristics

(Ia=25°C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	VF	IF=20mA	—	1.2	1.4	V
	Peak forward voltage	VFM	IFM=0.5A	—	3	4	V
	Reverse current	IR	VR=3V	—	—	10	μ A
Output	Collector-emitter dark current	ICEO	VCE=20V	—	1	100	nA
Transfer characteristics	Collector Current	IC	VCE=5V, IF=20mA	0.5	—	5	mA
	Collector saturation voltage	VCE(SET)	IF=40mA, IC=0.5mA	—	—	0.4	V
	Response time (Rise)	TR	VCE=2V, IC=2mA, RL=100 Ω	—	3	15	μ S
	Response time (Fall)	TF		—	4	20	μ S

